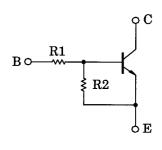
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1001,RN1002,RN1003 RN1004,RN1005,RN1006

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2001~RN2006

Equivalent Circuit and Bias Resister Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1001	4.7	4.7
RN1002	10	10
RN1003	22	22
RN1004	47	47
RN1005	2.2	47
RN1006	4.7	47

1. EMITTER 2. COLLECTOR 3. BASE JEDEC TO-92 EIAJ SC-43 TOSHIBA 2-5F1B

Weight: 0.21g

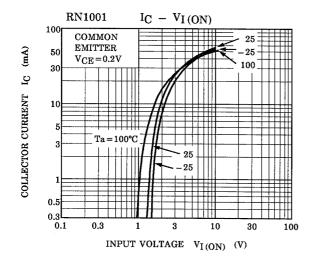
Maximum Ratings (Ta = 25°C)

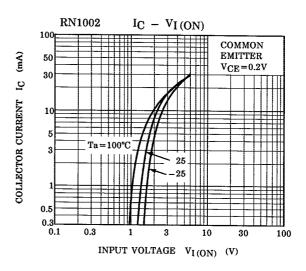
Characteristic		Symbol	Rating	Unit	
Collector-base voltage	RN1001~1006	V_{CBO}	50	V	
Collector-emitter voltage	10001-1000	V _{CEO}	50	V	
Emitter-base voltage	RN1001~1004	V _{EBO}	10	V	
	RN1005, 1006	vEBO	5		
Collector current	IC		100	mA	
Collector power dissipation	RN1001~1006	PC	400	mW	
Junction temperature	- KN 100 1~ 1000	Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

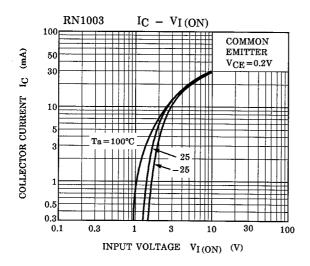


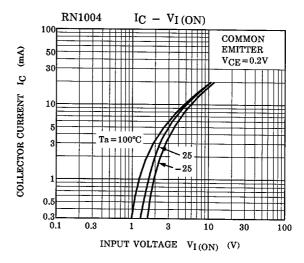
Electrical Characteristics (Ta = 25°C)

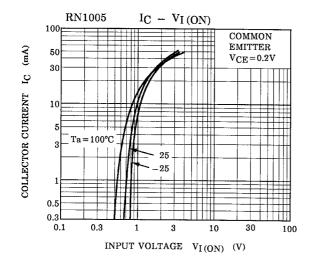
Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1001~1006	I _{CBO}	_	V _{CB} = 50V, I _E = 0	_	_	100	- nA
	1000			V _{CE} = 50V, I _B = 0	_	_	500	
Emitter cut-off current	RN1001	I _{EBO}	_	V _{EB} = 10V, I _C = 0	0.82	_	1.52	mA
	RN1002				0.38	_	0.71	
	RN1003				0.17	_	0.33	
	RN1004				0.082	_	0.15	
	RN1005			V - 5V I - 0	0.078	_	0.145	
	RN1006			V _{EB} = 5V, I _C = 0	0.074	_	0.138	
	RN1001				30	_	_	
DC current gain	RN1002				50	_	_	
	RN1003	h		\\- = E\\ = 10m \	70	_	_	_
	RN1004	h _{FE}	_	V_{CE} = 5V, I_C = 10mA	80	_	_	
	RN1005				80	_	_	
	RN1006				80	_	_	
Collector-emitter saturation voltage	RN1001~1006	V _{CE} (sat)	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
	RN1001			V _{CE} = 0.2V, I _C = 5mA	1.1	_	2.0	. V
	RN1002	Vi (on)	_		1.2	_	2.4	
Input voltage (ON)	RN1003				1.3	_	3.0	
	RN1004				1.5	_	5.0	
	RN1005				0.6	_	1.1	
	RN1006				0.7	_	1.3	
	RN1001~1004	V		V _{CE} = 5V, I _C = 0.1mA	1.0	_	1.5	V
Input voltage (OFF)	RN1005, 1006	V _{I (OFF)}	_		0.5	_	0.8	
Transition frequency	RN1001~1006	f _T	_	V _{CE} = 10V, I _C = 5mA	_	250	_	MH_z
Collector Output capacitance	RN1001~1006	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1MH _z	_	3	6	pF
	RN1001	R1 -			3.29	4.7	6.11	kΩ
	RN1002				7	10	13	
Input resistor	RN1003				15.4	22	28.6	
	RN1004		_		32.9	47	61.1	
	RN1005				1.54	2.2	2.86	
	RN1006				3.29	4.7	6.11	
Resistor ratio	RN1001~1004		R1/R2 —		0.9	1.0	1.1	_
	RN1005	R1/R2			0.0421	0.0468	0.0515	
	RN1006				0.09	0.1	0.11	

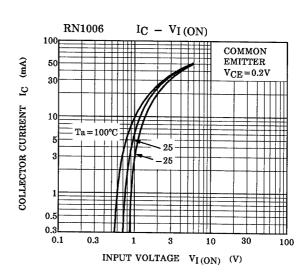


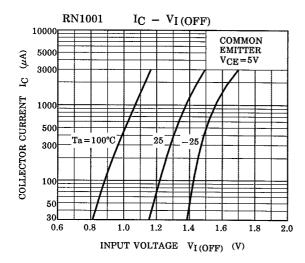


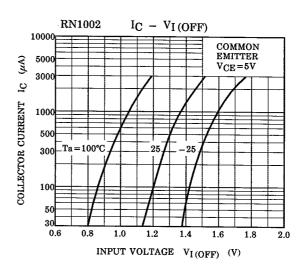


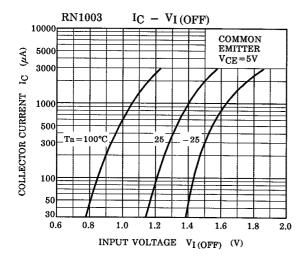


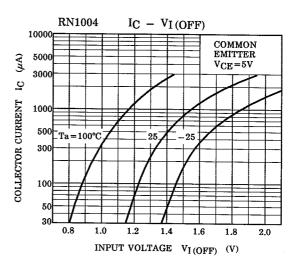


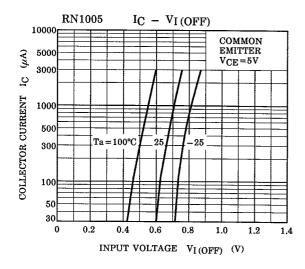


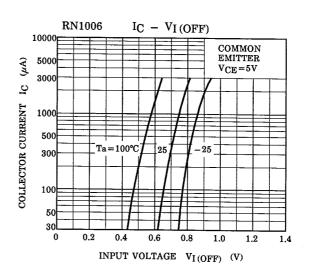


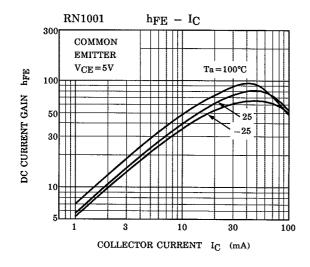


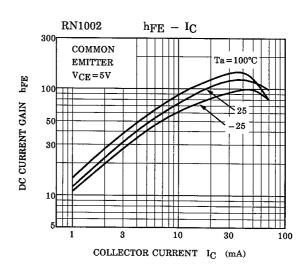


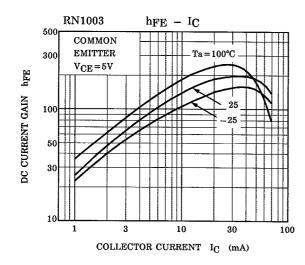


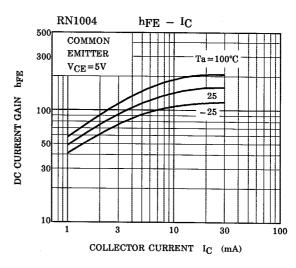


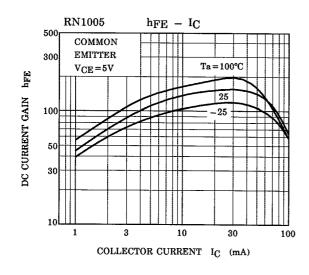


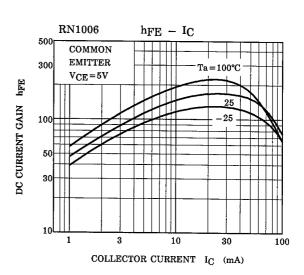












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